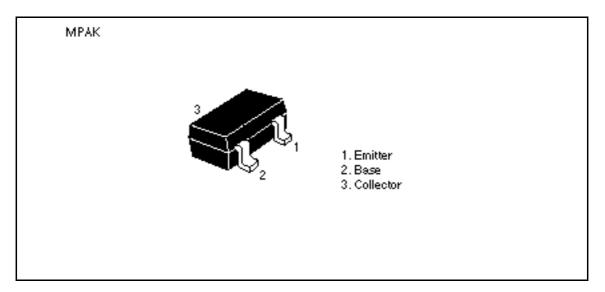
Silicon NPN Epitaxial

# HITACHI

#### Application

UHF / VHF wide band amplifier

#### Outline





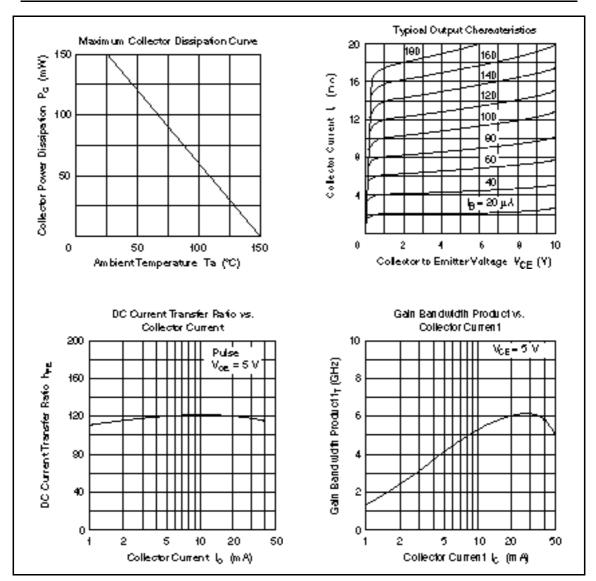
### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

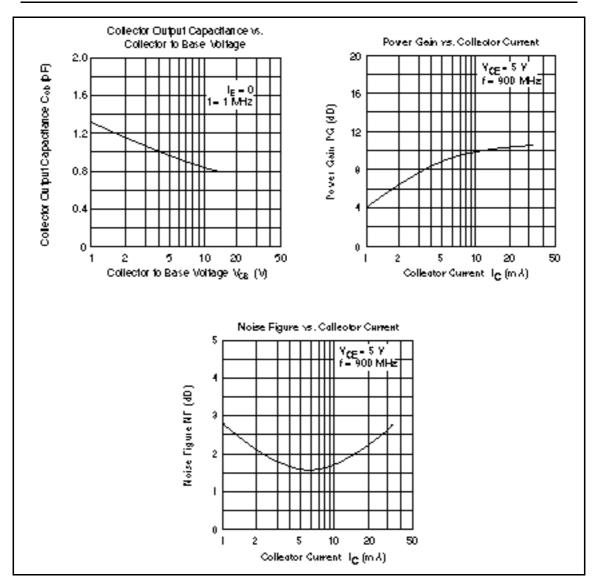
| Item                         | Symbol           | Ratings     | Unit |
|------------------------------|------------------|-------------|------|
| Collector to base voltage    | V <sub>CBO</sub> | 15          | V    |
| Collector to emitter voltage | V <sub>CEO</sub> | 11          | V    |
| Emitter to base voltage      | V <sub>EBO</sub> | 2           | V    |
| Collector current            | I <sub>c</sub>   | 50          | mA   |
| Collector power dissipation  | P <sub>c</sub>   | 150         | mW   |
| Junction temperature         | Тј               | 150         | °C   |
| Storage temperature          | Tstg             | –55 to +150 | °C   |

# **Electrical Characteristics** (Ta = $25^{\circ}$ C)

| Item                                | Symbol           | Min | Тур | Max | Unit | Test conditions  |
|-------------------------------------|------------------|-----|-----|-----|------|--|
| Collector to base breakdown voltage | $V_{(BR)CBO}$    | 15  | _   | _   | V    | $I_{c} = 10 \ \mu A, \ I_{e} = 0$  |
| Collector cutoff current            | I <sub>CEO</sub> | _   | _   | 1   | μA   | $V_{ce}$ = 10 V, $R_{be}$ =  |
| Emitter cutoff current              | I <sub>EBO</sub> | _   | _   | 1   | μA   | $V_{EB} = 1 V, I_{C} = 0$  |
| Collector cutoff current            | I <sub>CBO</sub> | _   | _   | 1   | μA   | $V_{_{CB}} = 12 \text{ V}, \text{ I}_{_{E}} = 0$                           |
| DC current transfer ratio           | $h_{FE}$         | 50  | 120 | 250 |      | $V_{ce}$ = 5 V, $I_c$ = 20 mA  |
| Collector output capacitance        | Cob              | _   | 1.0 | 1.5 | pF   | $V_{_{CB}} = 5 \text{ V}, \text{ I}_{_{E}} = 0, \text{ f} = 1 \text{ MHz}$ |
| Gain bandwidth product              | f <sub>T</sub>   | _   | 6.0 | _   | GHz  | $V_{ce}$ = 5 V, I <sub>c</sub> = 20 mA                                     |
| Power gain                          | PG               | _   | 10  | _   | dB   | $V_{ce} = 5 \text{ V}, \text{ I}_{c} = 20 \text{ mA},$<br>f = 900 MHz      |
| Noise figure                        | NF               | _   | 1.6 | —   | dB   | $V_{ce} = 5 V, I_c = 5 mA,$<br>f = 900 MHz                                 |

Note: Marking is "IS-".





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